

FORM PTO-1449

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2132.0070002APPLICATION NO.
10/674,071

INFORMATION DISCLOSURE STATEMENT

INVENTORS
EMPEDOCLES *et al.*FILING DATE
September 30, 2003ART UNIT
2632 2876

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB-CLASS	FILING DATE
DA	AA1	2001/0054709 A1	12/2001	Heath <i>et al.</i>			
	AB1	2002/0130311 A1	09/2002	Lieber <i>et al.</i>			
	AC1	2002/0130353 A1	09/2002	Lieber <i>et al.</i>			
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						

FOREIGN PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION
	AJ						Yes No
	AK						Yes No
	AL						Yes No
	AM						Yes No

OTHER (Including Author, Title, Date, Pertinent Pages, etc.)

DA	AN	1	Chung, S.-W. <i>et al.</i> , "Silicon nanowire devices," <i>Applied Physics Letters</i> , Vol. 76, No. 15, pp. 2068-2070 (April 10, 2000). 1026				
	AO	1	Duan, X. <i>et al.</i> , "High-performance thin-film transistors using semiconductor nanowires and nanoribbons," <i>Nature</i> , Vol. 425, pp. 274-278 (September 18, 2003).				
	AP	1	Tans, S.J. <i>et al.</i> , "Room-temperature transistor based on a single carbon nanotube," <i>Nature</i> , Vol. 393, pp. 49-52 (May 7, 1998). 1126				
	AQ	1	Yamada, T., "Analysis of submicron carbon nanotube field-effect transistors," <i>Applied Physics Letters</i> , Vol. 76, No. 5, pp. 628-630 (January 31, 2000). 1126				

EXAMINER

DATE CONSIDERED 8/31/2005

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.